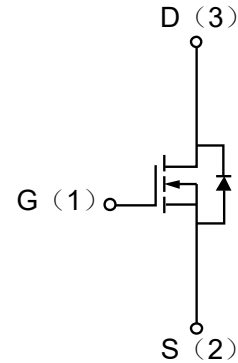


Description

The MOSFET provide the best combination of fast switching, low on-resistance and cost-effectiveness.

MOSFET Product Summary		
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)
20	0.043@ V _{GS} =4.5V	3


Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
OFF/ON CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250μA, V _{GS} =0V	20		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±8V	-	-	±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.6	-	1.2	V
Static Drain-Source On-Resistance ²	R _{DS(ON)}	V _{GS} =4.5V, I _D =2.8A	-	0.043	0.060	Ω
		V _{GS} =2.5V, I _D =2.0A	-	0.052	0.115	Ω
DYNAMIC PARAMETERS						
Input Capacitance	C _{ISS}	V _{GS} =0V, V _{DS} =10V, f=1MHz	-	450		pF
Output Capacitance	C _{OSS}		-	70		pF
Reverse Transfer Capacitance	C _{RSS}		-	43		pF
SWITCHING PARAMETERS						
Turn-On Delay Time	t _{d(on)}	V _{DS} =10V, V _{GS} =4.5V, R _G =6Ω, I _D =1A	-	7	15	ns
Turn-Off Delay Time	t _{d(off)}		-	16	60	ns
Turn-On Rise Time	T _r		-	55	80	ns
Turn-On Fall Time	T _f		-	20	25	ns
Total Gate Charge	Q _g (10)	V _{DS} =10V, V _{GS} =4.5V, I _D =3.6A		5.2	10	nC
Gate-Source Charge	Q _{gs}			0.65		nC
Gate-Drain Charge	Q _{gd}			1.5		nC
Drain-Source Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =1.0A		0.76	1.2	V
Maximum Continuous Drain-Source Diode Forward Current	I _S				1.6	A

Absolute maximum rating@25°C

Parameter		Symbol	Value	Units	
Drain-Source Voltage		V_{DS}	20	V	
Gate-Source Voltage		V_{GS}	± 8	V	
Drain Current	Continuous	I_D	3	A	
	Pulsed	I_D	9	A	
Total Power Dissipation		P_D	1.25	W	
Operating Junction and Storage Temperature Range		T_J	-55 to 150	°C	
Thermal Characteristics					
Parameter		Symbol	Typ	Max	Units
Maximum Junction-to-Ambient A	$t \leq 10s$	θ_{JA}	-	100	°C/W

Typical Characteristics

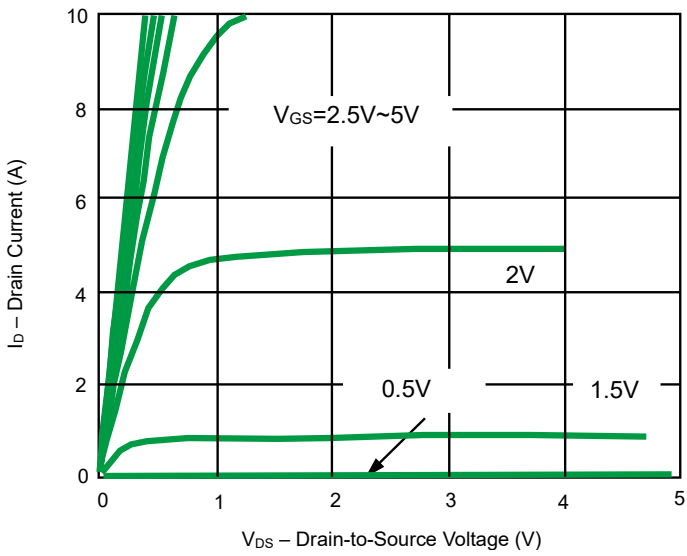


Fig 1. Output Characteristics

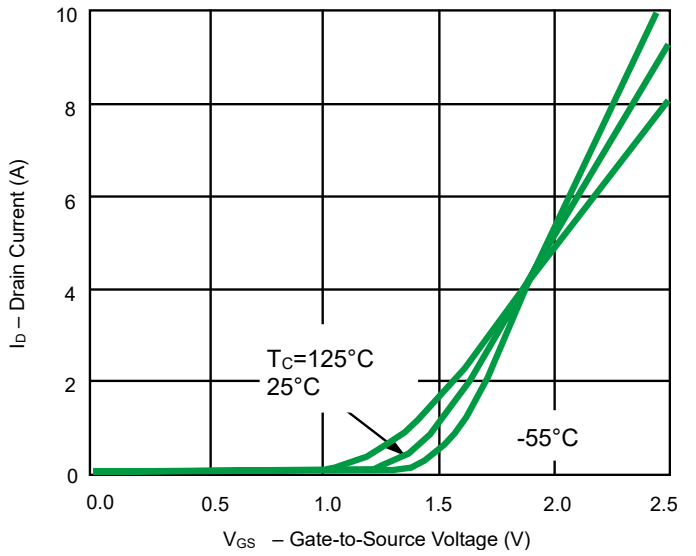


Fig 2. Transfer Characteristics

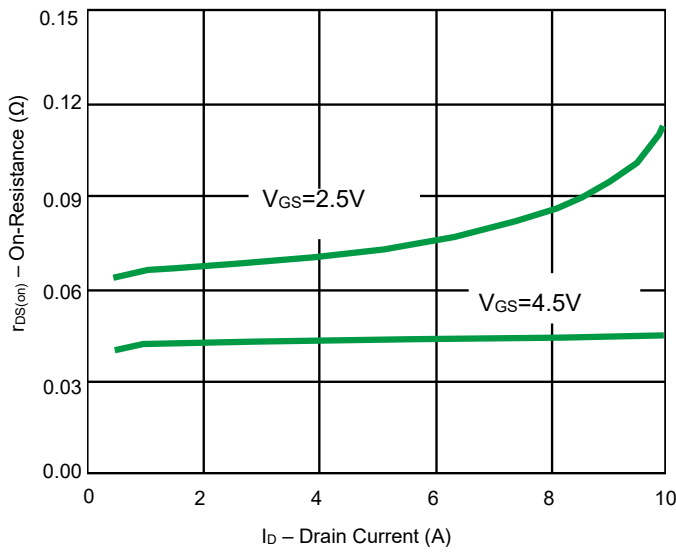


Fig 3. On-Resistance vs. Drain Current

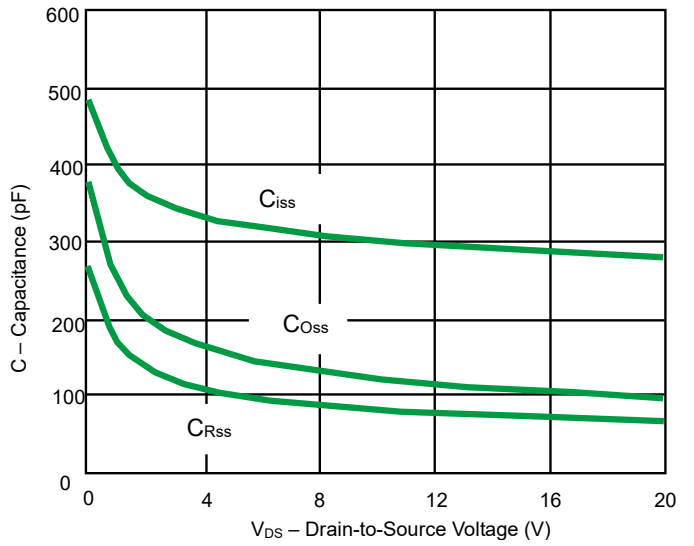


Fig 4. Capacitance Characteristics

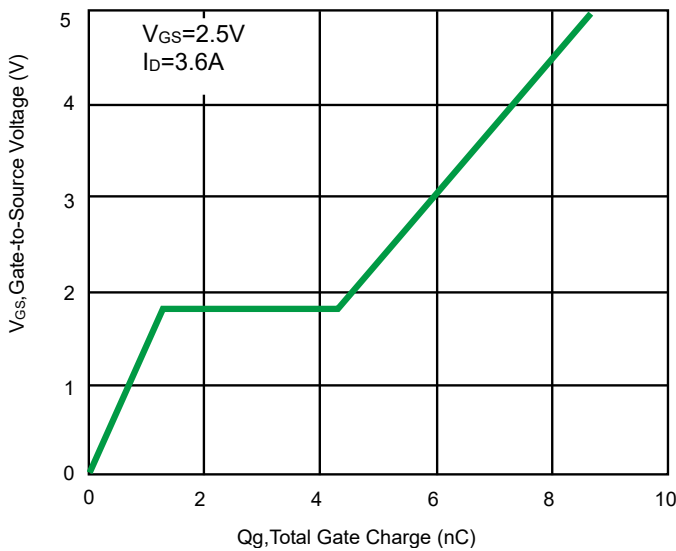


Fig 5. Gate Charge Characteristics

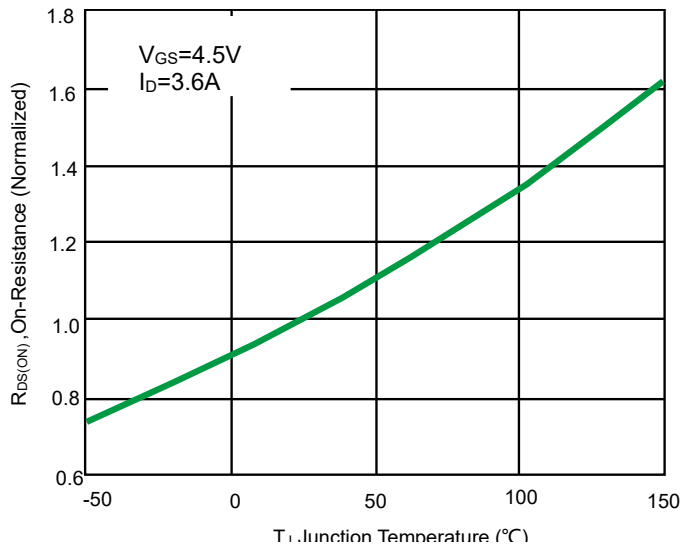


Fig 6. On-Resistance vs. Junction Temperature

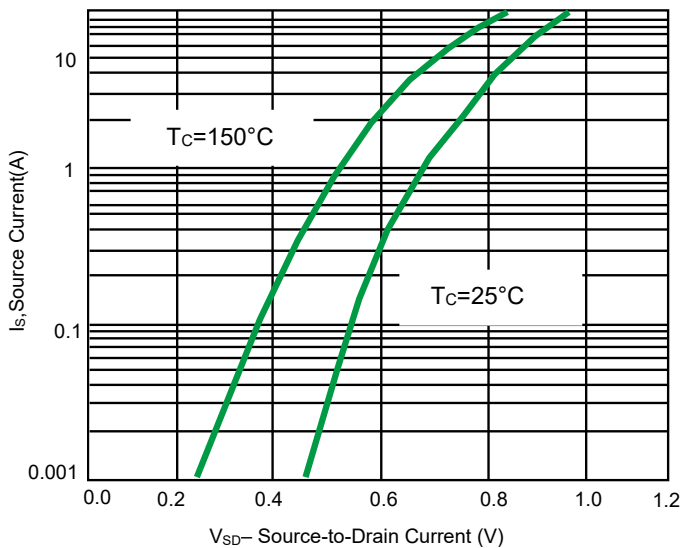


Fig 7. Source-Drain Diode Forward Voltage

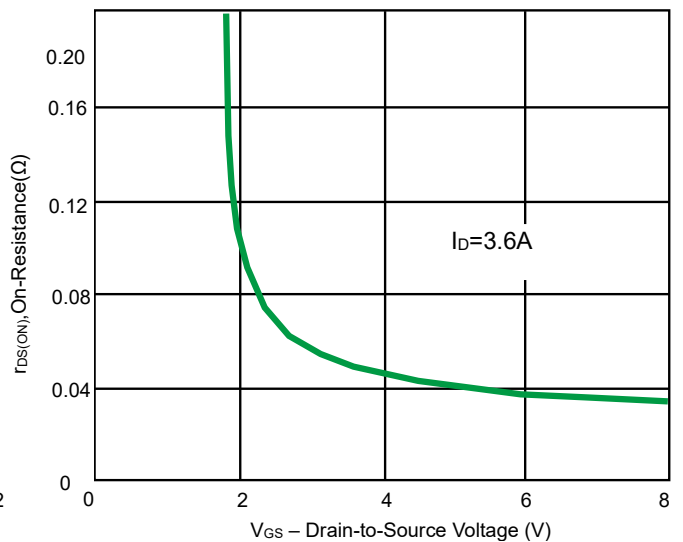


Fig 8. On-Resistance vs. Gate-to-Source Voltage

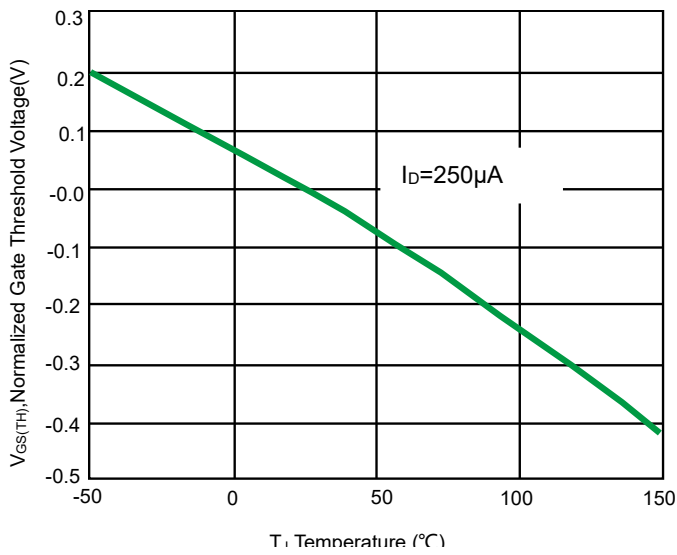


Fig 9. Normalized Gate Threshold Voltage vs. Temperature

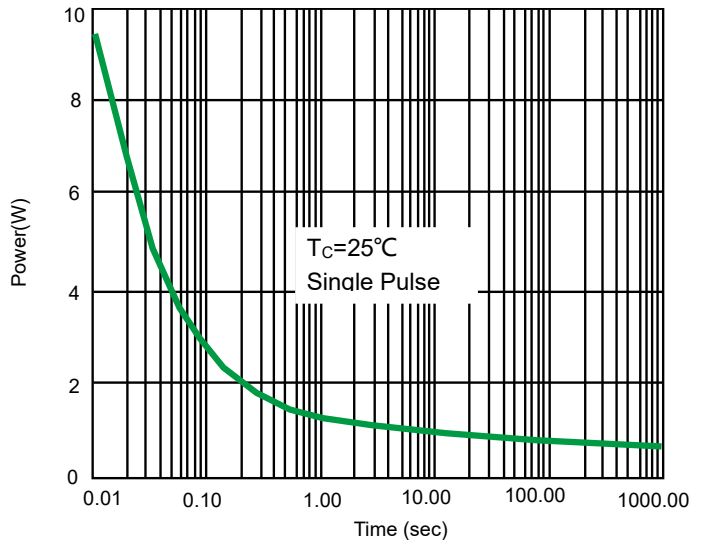
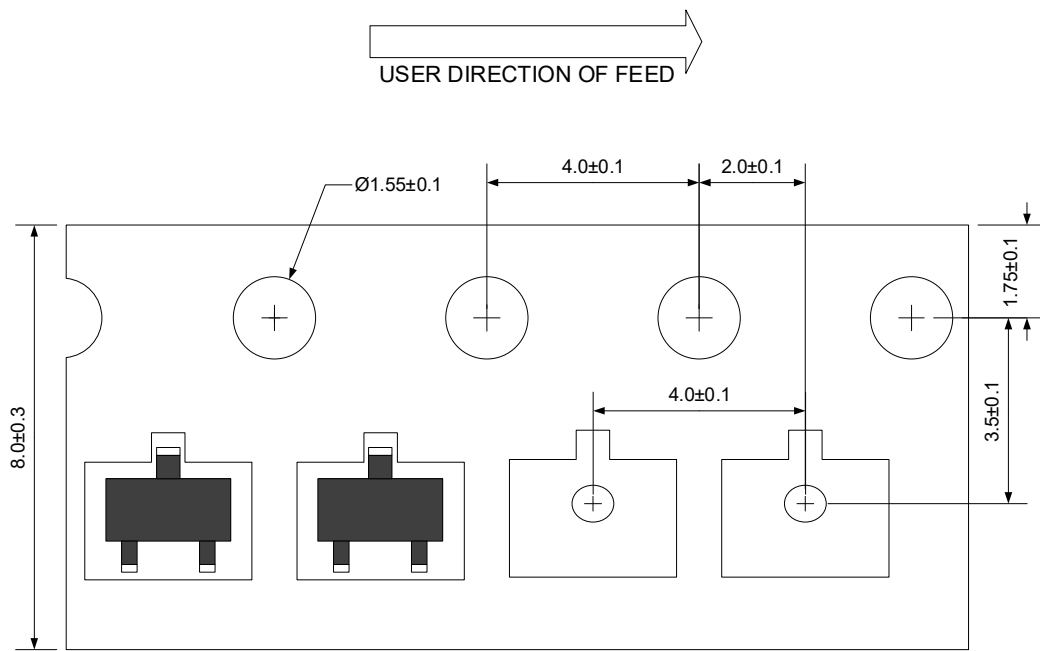


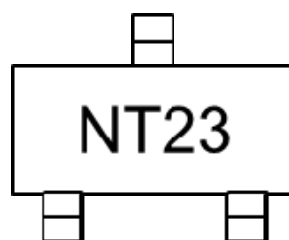
Fig 10. Single Pulse Power

Load with information

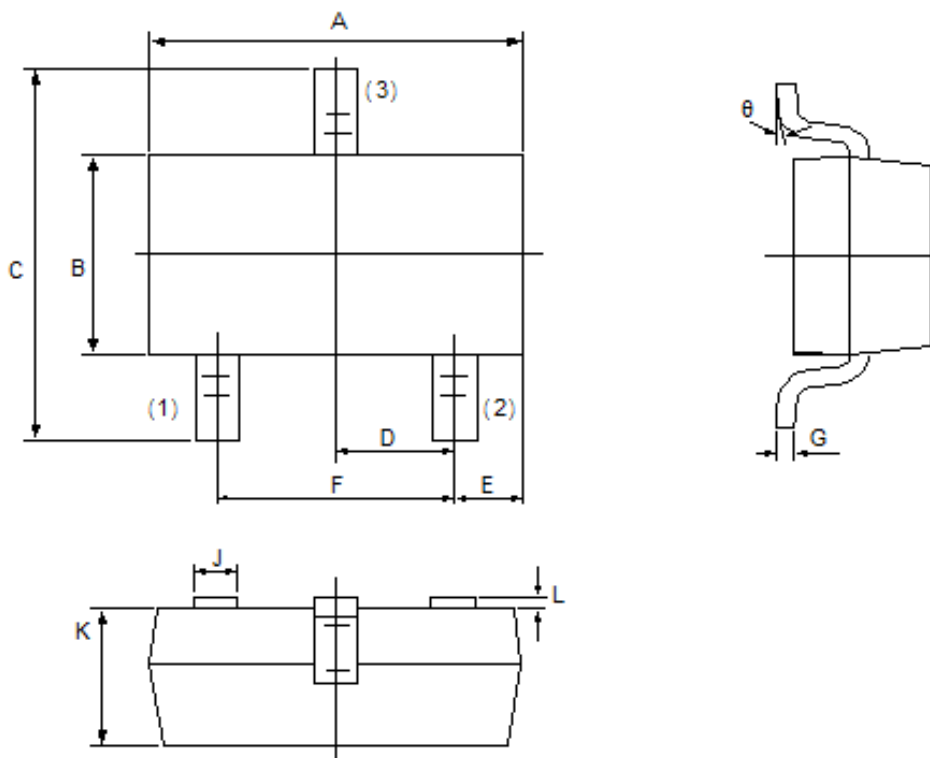


Unit:mm

Marking information



Product dimension(SOT-23)




Dim	Millimeters		Inches	
	MIN	MAX	MIN	MAX
A	2.72	3.12	0.107	0.123
B	1.10	1.50	0.043	0.059
C	2.10	2.64	0.083	0.104
D	0.95 BSC		0.037 BSC	
E	0.50 BSC		0.020 BSC	
F	1.90 BSC		0.075 BSC	
G	0.08	0.21	0.003	0.008
J	0.30	0.50	0.012	0.020
K		1.35		0.053
L	0.013	0.15	0.001	0.006
θ	0°	10°	0°	10°

Ordering information

Device	Package	Reel	Shipping
PNMT20V3	SOT-23 (Pb-Free)	7"	3000 / Tape & Reel


IMPORTANT NOTICE

 and **Prisemi**[®] are registered trademarks of **Prisemi Electronics Co., Ltd (Prisemi)** ,Prisemi reserves the right to make changes without further notice to any products herein. Prisemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Prisemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. “Typical” parameters which may be provided in Prisemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including “Typicals” must be validated for each customer application by customer’s technical experts. Prisemi does not convey any license under its patent rights nor the rights of others. The products listed in this document are designed to be used with ordinary electronic equipment or devices, Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

Website: <http://www.prisemi.com>

For additional information, please contact your local Sales Representative.

©Copyright 2009, Prisemi Electronics

 **Prisemi**[®] is a registered trademark of Prisemi Electronics.

All rights are reserved.